## **MA4X7240G**

### Silicon epitaxial planar type

For super high speed switching For small current rectification

#### ■ Features

- Two isolated elements are contained in one package, allowing high-density mounting
- Two MA3X721 is contained in one package (of a type in the same direction)
- Forward current (Average)  $I_{F(AV)} = 200 \text{ mA}$  rectification is possible

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

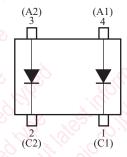
Parameter		Symbol	Rating	Unit	
Reverse voltage		$V_R$	30	V	
Repetitive peak reverse voltage		V <sub>RRM</sub>	30	V	
Peak forward	Single	$I_{FM}$	300	mA	
current	Double *1		225		
Forward current	Single	I <sub>F(AV)</sub>	200	mA	
(Average)	Double *1		150		
Non-repetitive peak	Single	I <sub>FSM</sub>	1	A	
forward surge current *2	Double *1		0.75	40/103	
Junction temperature		T <sub>j</sub>	150	C°C V	
Storage temperature		T <sub>stg</sub>	-55 to +150	°C	

Note) \*1: Value of each diode in double diodes used.

#### Package

- Code Mini4-G3
- Pin Name
  - 1: Cathode 1
  - 2: Cathode 2
  - 3: Anode 2
  - 4: Anode 1
- Marking Symbol: M1T

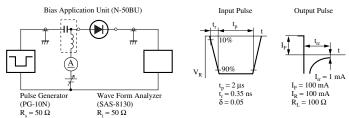
#### ■ Internal Connection



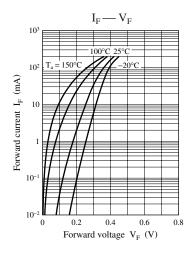
#### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

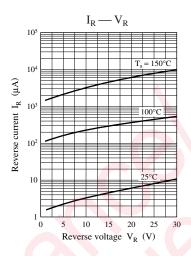
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\mathrm{F}}$	I <sub>F</sub> = 200 mA			0.55	V
Reverse current	$I_R$	$V_R = 30 \text{ V}$			50	μΑ
Terminal capacitance	C <sub>t</sub>	$V_R = 0 \text{ V, f} = 1 \text{ MHz}$		30		pF
Reverse recovery time *	t <sub>rr</sub>	$I_F = I_R = 100 \text{ mA}$		3.0		ns
		$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

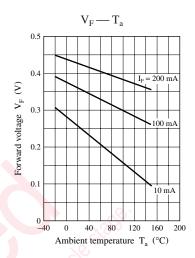
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 1 GHz.
  - 4. \*: t<sub>rr</sub> measurement circuit

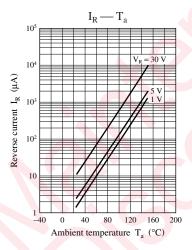


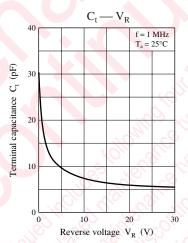
<sup>\*2:</sup> The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)





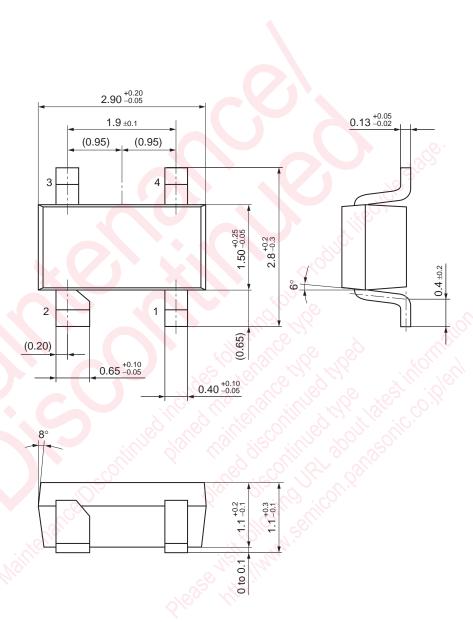






2 SKF00107AED

Mini4-G3 Unit: mm



SKF00107AED 3

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